

SMT660

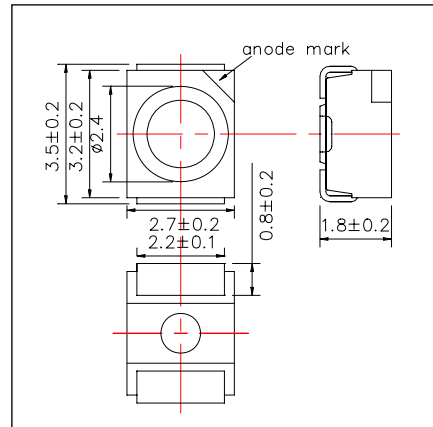
High Performance Red Color TOP LED

SMT660 consists of an AlGaInP LED mounted on the lead frame as TOP LED package and is 110mcd of brightness.
It emits a spectral band of radiation at 650nm.

<Specifications>

1. Product Name: TOP LED
2. Type Number: SMT660
3. Chip:
 - Chip Material: AlGaInP
 - Peak Wav
4. Package
 - Lead Frame Die: Silver Plated
 - Package Resin: PPA Resin
 - Lens: Epoxy Resin

Outer Dimension (Unit:mm)



Absolute Maximum Ratings				
Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature
Power Dissipation	PD	120	mW	Ta=25°C
Forward Current	IF	50	mA	Ta=25°C
Reverse Voltage	VR	5	V	Ta=25°C
Operating Temperature	TOPR	-20 ~ +80	°C	
Storage Temperature	TSTG	-30 ~ +80	°C	
Soldering Temperature*	TSOL	240	°C	

* Soldering condition must be completed within 3 second at 230 °C.

Electro-Optical Characteristics [Ta=25°C typ.]						
Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	VF	IF=20mA		1.90	2.30	V
Reverse Current	IR	VR=5V			10	uA
Total Radiated Power*	PO	IF=20mA	2.2	3.5		mW
Brightness**	IV	IF=20mA	50	110		mcd
Peak Wavelength	λP	IF=20mA	640	650	660	nm
Half Width	Δλ	IF=20mA		20		nm
Viewing Half Angle	θ1/2	IF=20mA		± 55		deg

* Measured by Photodyne #500

** Measured by Tektronix J-16

